

DTC114EE to DTC123JE NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

General description

SOT-523 Bias Resistor Transistor. NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network.

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors: a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The device is 3 designed for low power surface mount applications.

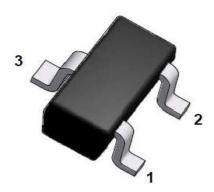
FEATURES

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- RoHS Compliant
- Green EMC
- Matte Tin(Sn) Lead Finish
- Weight: approx. 0.002g

Absolute Maximum Ratings (T_A = 25°C unless otherwise noted)

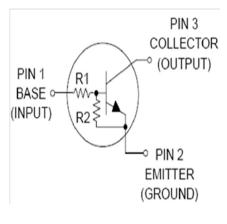
Symbol	Parameter	Value	Units	
V _{СВО}	Collector-Base Voltage	50	V	
V CEO	Collector-Emitter Voltage	50	V	
Ic	Collector Current	100	mA	
P _D	Power Dissipation	150	mW	
Reja	Thermal Resistance from Junction to Ambient	600	°C /W	
Тл Тэтс	Junction & Storage Temperature Range	-55 to +150	°C	

Green Product



SOT-523 (SC-75A)

Electrical Symbol:





Device Marking & Resistor Values:

Device	Marking	R1 (KΩ)	R2 (KΩ)
DTC114EE	24	10	10
DTC124EE	25	22	22
DTC144EE	26	47	47
DTC114YE	64	10	47
DTC114TE	04	10	∞
DTC143TE	03	4.7	∞
DTC123EE	22	2.2	2.2
DTC143EE	23	4.7	4.7
DTC143ZE	E23	4.7	47
DTC124XE	45	22	47
DTC123JE	E42	2.2	47

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Off Characteristics

Symbol	Parameter	Test Condition	Limits			
			Min	Тур	Max	Unit
Ісво	Collector-Base Cutoff Current	V _{CB} =50V, I _E =0A	-	-	100	nA
ICEO	Collector-Emitter Cutoff Current	V _{CE} =50V, I _B =0A	-	-	500	nA
Ієво	Emitter-Base Cutoff Current DTC114EE DTC124EE DTC144EE DTC114YE DTC114TE DTC1143TE DTC123EE DTC143EE DTC143ZE DTC124XE DTC123JE	V _{EB} =6.0V, I _C =0A	- 	- 	0.50 0.20 0.10 0.20 0.90 1.90 2.30 1.50 0.18 0.13	mA
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I _C =10uA, I _E =0A	50	-	_	Volts
V(BR)CEO	Collector-Emitter Breakdown Voltage (Note 1)	I _C =2.0mAA, I _B =0A	50	-	-	Volts

Note 1: Pulse Test. Pulse width <300us, Duty cycle < 2.0%)



On Characteristics (Note 1)

Oli C	Parameter Test Condition		Limits			
Symbol		Test Condition	Min	Тур	Max	Unit
	DC Current Dain					
	DTC114EE		35	60		
	DTC124EE		60	100		
	DTC144EE		80	140		
	DTC114YE		80	140		
H _{FE}	DTC114TE	$V_{CE} = 10V, I_{C} = 5.0 \text{mA}$	160	350		
ΠFE	DTC143TE	VCE - 10V, 1C - 3.0111A	160	350		
	DTC123EE		8.0	15		
	DTC143EE		15	30		
	DTC143ZE		80	200		
	DTC124XE		80	150		
	DTC123JE		80	140		
	Collector-Emitter Saturation Voltage					
	DTC114EE	I _C =10mA, I _B =0.3mA			0.25	Volts
	DTC124EE	I _C =10mA, I _B =0.3mA				
	DTC144EE	I _C =10mA, I _B =0.3mA				
	DTC114YE	I _C =10mA, I _B =0.3mA I _C =10mA, I _B =1mA				
VCE(sat)	DTC114TE					
₩ CE(Sat)	DTC143TE	I _C =10mA, I _B =1mA				
	DTC123EE	I _C =10mA, I _D =5mA				
	DTC143EE	I _C =10mA, I _D =1mA				
	DTC143ZE	Ic=10mA, I _D =1mA				
	DTC124XE	I _C =10mA, I _B =1mA				
	DTC123JE	I _C =10mA, I _B =0.3mA				
	Output Voltage (on)	R _L = 1.0KΩ				
	DTC114EE	V _{CC} =5.0V, V _B =2.5V				Malka
	DTC124EE	V _{CC} =5.0V, V _B =2.5V V _{CC} =5.0V,				
	DTC144EE	V _B =3.5V V _{CC} =5.0V, V _B =2.5V				
	DTC114YE	·				
W	DTC114TE	V _{CC} =5.0V, V _B =2.5V			0.55	
V ol	DTC143TE	V _{CC} =5.0V, V _B =2.5V			0.20	Volts
	DTC123EE	V _{CC} =5.0V, V _B =2.5V				
	DTC143EE	V _{CC} =5.0V, V _B =2.5V				
	DTC143ZE	V _{CC} =5.0V, V _B =2.5V				
	DTC124XE	V _{CC} =5.0V, V _B =2.5V				
	DTC123JE	V _{CC} =5.0V, V _B =2.5V				



On Characteristics

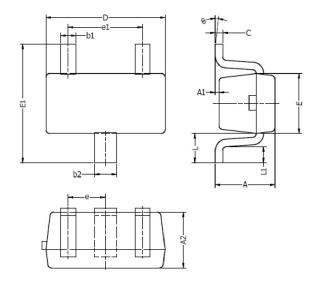
Symbol	Parameter	Test Condition	Limits			Unit
- ,			Min	Тур	Max	
V он	Output Voltage (on) DTC114EE DTC124EE DTC144EE DTC114YE DTC114TE DTC143TE DTC123EE DTC143ZE DTC124XE DTC123JE	R_L = 1.0 $K\Omega$ V_{CC} =5.0 V , V_B =0.5 V V_{CC} =5.0 V , V_B =0.5 V V_{CC} =5.0 V , V_B =0.5 V V_{CC} =5.0 V , V_B =0.25 V V_{CC} =5.0 V , V_B =0.25 V V_{CC} =5.0 V , V_B =0.5 V	4.9	T		Volts

Electrical Characteristics (TA = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Тур	Max	Unit
R1	Input Resistor				
	DTC114EE	7.0	10	13	
	DTC124EE	15.4	22	28.6	
	DTC144EE	32.9	47	61.1	
	DTC114YE	7.0	10	13	
	DTC114TE	7.0	10	13	ΚΩ
	DTC143TE	3.3	4.7	6.1	KΩ
	DTC123EE	1.5	2.2	2.9	
	DTC143EE	3.3	4.7	6.1	
	DTC143ZE	3.3	4.7	6.1	
	DTC124XE	15.4	22	28.6	
	DTC123JE	1.54	2.2	2.86	
R1/R2	Resistor Ratio				
	DTC114EE	0.8	1.0	1.2	
	DTC124EE	0.8	1.0	1.2	
	DTC144EE	0.8	1.0	1.2	
	DTC114YE	0.17	0.21	0.25	
	DTC114TE	-	-	-	
	DTC143TE	-	-	-	
	DTC123EE	0.8	1.0	1.2	
	DTC143EE	0.8	1.0	1.2	
	DTC143ZE	0.055	0.1	0.185	
	DTC124XE	0.38	0.47	0.56	
	DTC123JE	0.038	0.047	0.056	

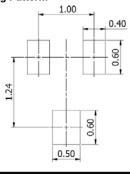


SOT-523 Package Outline



DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
А	0.70	0.90	0.028	0.035	
A1	0.00	0.10	0.000	0.004	
A2	0.70	0.80	0.028	0.031	
b1	0.15	0.25	0.006	0.010	
b2	0.25	0.35	0.010	0.014	
С	0.10	0.20	0.004	0.008	
D	1.50	1.70	0.059	0.067	
E	0.70	0.90	0.028	0.035	
E1	1.45	1.75	0.057	0.069	
е	0.50	TYP.	0.020	TYP.	
e1	0.90	1.10	0.035	0.043	
L	0.40 REF.		0.016	REF.	
L1	0.10	0.30	0.004	0.012	
θ	0 °	8°	0 °	8°	

Typical Soldering Pattern:



Note:

- 1. Above package outline conforms to JEITA EAIJ ED-7500A SC-75A.
- 2. Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.



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